

# BCR12LM-16LH

Triac Medium Power Use R07DS0415EJ0100 Rev.1.00 May 19, 2011

### **Features**

I<sub>T (RMS)</sub>: 12 A
 V<sub>DRM</sub>: 800 V

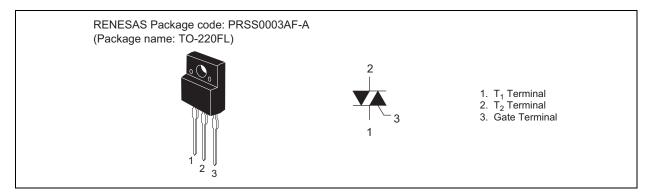
 $\bullet \quad I_{FGTI},\,I_{RGTI},\,I_{RGT\,III}\colon 50\;mA\;or\;35mA\;(I_{GT}\,item:1)$ 

High Commutation

 $\bullet$   $V_{iso}: 1800V$ 

- The Product guaranteed maximum junction temperature 150°C
- Insulated Type
- Planar Type

### **Outline**



## **Applications**

Switching mode power supply, washing machine, motor control, heater control, and other general purpose AC power control applications

# **Maximum Ratings**

Parameter	Cumbal	Voltage class	Unit	
Farameter	Symbol	16	Onit	
Repetitive peak off-state voltage <sup>Note1</sup>	$V_{DRM}$	800	V	
Non-repetitive peak off-state voltage <sup>Note1</sup>	$V_{DSM}$	960	V	

Notes: 1. Gate open.

Parameter	Symbol	Ratings	Unit	Conditions
RMS on-state current	I <sub>T (RMS)</sub>	12	Α	Commercial frequency, sine full wave
				360°conduction, Tc = 93°C
Surge on-state current	I <sub>TSM</sub>	120	Α	60 Hz sinewave 1 full cycle, peak value,
				non-repetitive
I <sup>2</sup> t for fusion	l <sup>2</sup> t	60	$A^2s$	Value corresponding to 1 cycle of half
				wave 60 Hz, surge on-state current
Peak gate power dissipation	$P_{GM}$	5	W	
Average gate power dissipation	P <sub>G (AV)</sub>	0.5	W	
Peak gate voltage	$V_{GM}$	10	V	
Peak gate current	$I_{GM}$	2	Α	
Junction Temperature	Tj	-40 to +150	°C	
Storage temperature	Tstg	-40 to +150	°C	
Mass	_	1.5	g	Typical value
Isolation voltage	V <sub>iso</sub>	1800	V	Ta = 25°C, AC 1 minute,
				T <sub>1</sub> • T <sub>2</sub> • G terminal to case

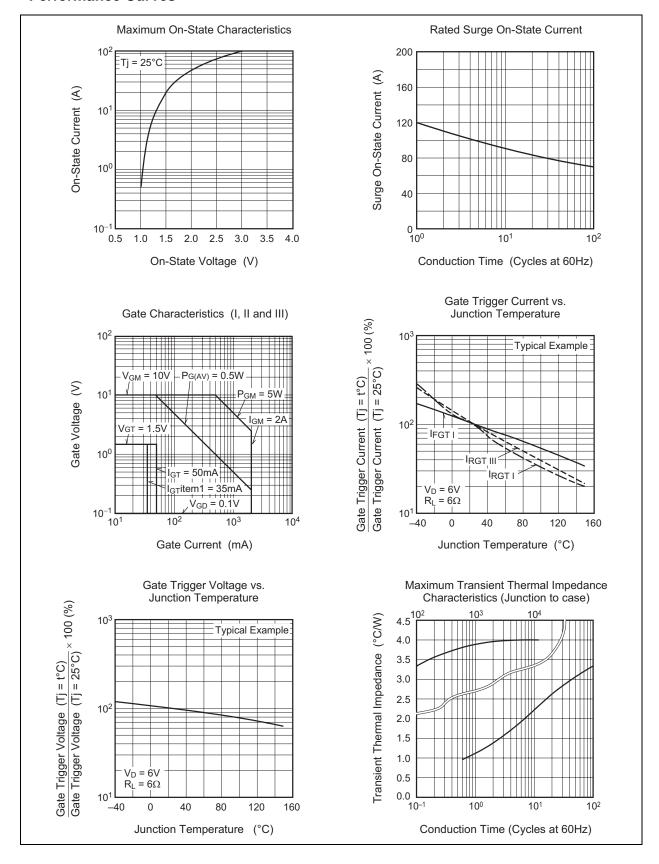
# **Electrical Characteristics**

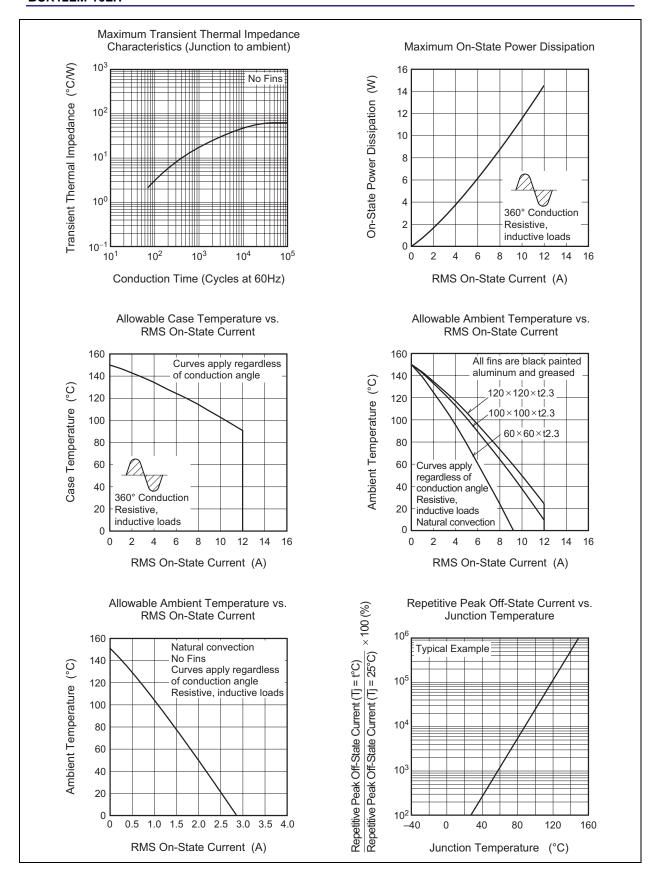
Parameter		Symbol	ol BCR12LM-16LH-1 (I <sub>GT</sub> item : 1)		BCR12LM-16LH			Unit	Test conditions	
			Min.	Тур.	Max.	Min.	Тур.	Max.		
Repetitive peak off-state co	urrent	I <sub>DRM</sub>	I	_	2.0	l	l	2.0	mA	Tj = 150°C V <sub>DRM</sub> applied
On-state voltage		V <sub>TM</sub>	ı	_	1.5	ı	1	1.5	V	Tc = 25°C, I <sub>TM</sub> = 20 A instantaneous measurement
Gate trigger voltage <sup>Note2</sup>	I	$V_{\text{FGTI}}$	_	_	1.5	_	_	1.5	V	$Tj = 25^{\circ}C, V_D = 6 V$
	II	$V_{RGTI}$	_	_	1.5	_	_	1.5	V	$R_L = 6 \Omega$ , $R_G = 330 \Omega$
	III	$V_{RGTIII}$	_	_	1.5	_	_	1.5	V	
Gate trigger curent <sup>Note2</sup>	I	I <sub>FGTI</sub>	_	_	35	_	_	50	mA	Tj = 25°C, V <sub>D</sub> = 6 V
	II	I <sub>RGTI</sub>	_	_	35	_	_	50	mA	$R_L = 6 \Omega$ , $R_G = 330 \Omega$
	III	$I_{RGT_{III}}$	_	_	35	_	_	50	mA	
Gate non-trigger voltage		$V_{GD}$	0.2	_	_	0.2	_	_	V	$Tj = 125^{\circ}C$ $V_D = 1/2 V_{DRM}$
			0.1	_	_	0.1	_	_	V	$Tj = 150^{\circ}C$ $V_D = 1/2 V_{DRM}$
Thermal resistance		R <sub>th (j-c)</sub>	_	_	4.0	_	_	4.0	°C/W	Junction to case <sup>Note3</sup>
Critical-rate of decay of on commutating current Note4	-state	(di/dt)c	7	_	_	13	_	_	A/ms	Tj = 125°C (dv/dt)c < 100 V/μs

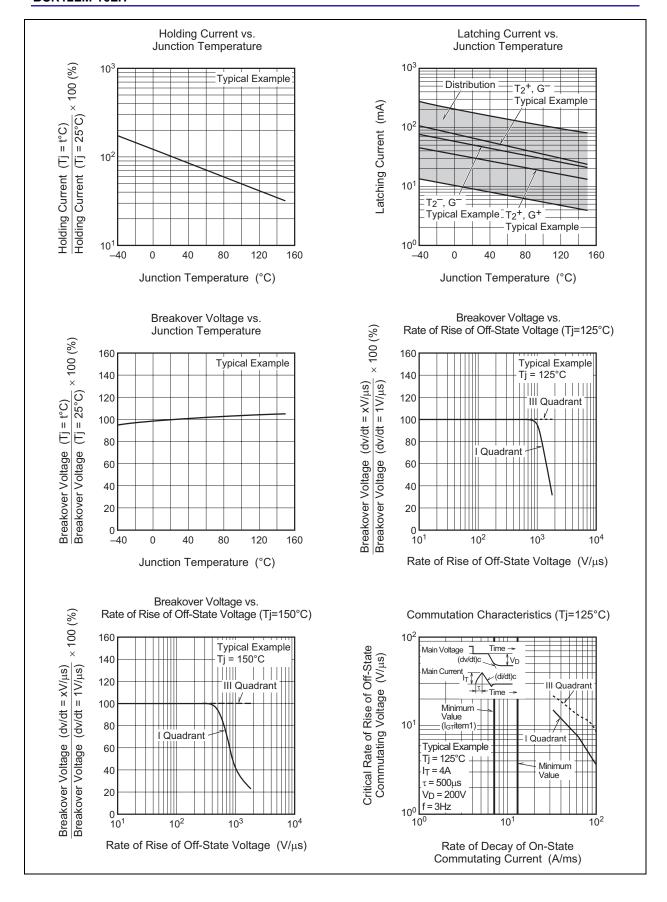
- Notes: 2. Measurement using the gate trigger characteristics measurement circuit.
  - 3. The contact thermal resistance  $R_{\text{th (c-f)}}$  in case of greasing is 0.5°C/W.
  - 4. Test conditions of the critical-rate of decay of on-state commutation current are shown in the table below.

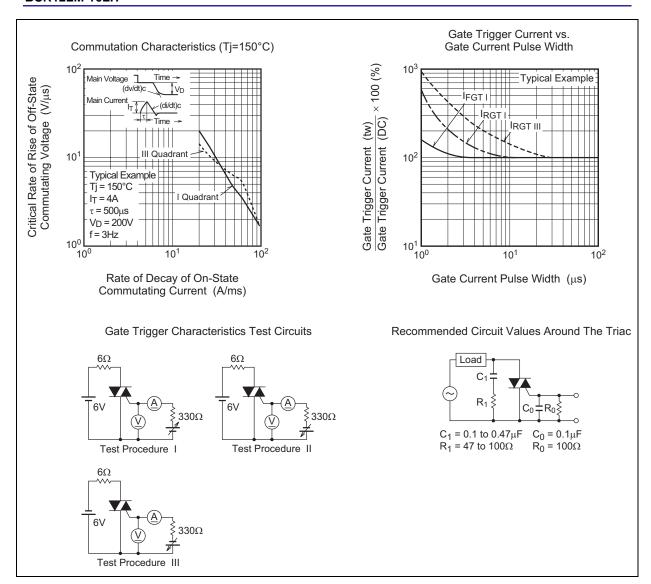
Test conditions	Commutating voltage and current waveforms (inductive load)
1. Junction temperature Tj = 125°C	Supply Voltage  → Time
2. Peak off-state voltage V <sub>D</sub> = 400 V	Main Current (di/dt)c → Time
2. Rate of rise of off-state commutating voltage (dv/dt)c < 100 V/μs	Main Voltage Time

### **Performance Curves**

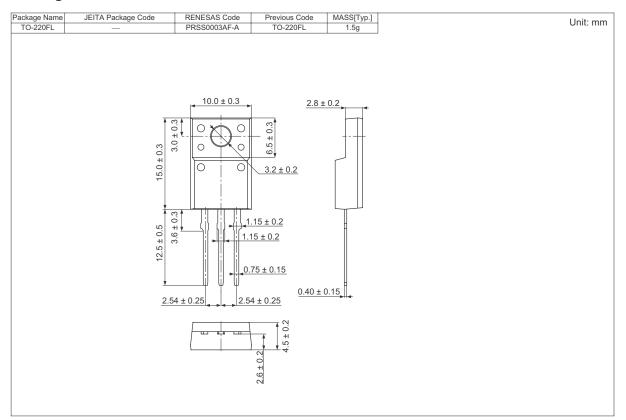








# **Package Dimensions**



# **Ordering Information**

Orderable Part Number	Packing	Quantity	Remark
BCR12LM-16LH#B00	Tube	50 pcs.	Straight type
BCR12LM-16LH-1#B00	Tube	50 pcs.	Straight type, I <sub>GT</sub> item:1

Note: Please confirm the specification about the shipping in detail.

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Renesas Electronics America Inc. 2880 Scott Boulevard Santa Clara, CA 95050-2554, U.S.A. Tel: +1-408-588-6000, Fax: +1-408-588-6130

Renesas Electronics Canada Limited

1101 Nicholson Road, Newmarket, Ontario L3Y 9C3, Canada Tel: +1-905-898-5441, Fax: +1-905-898-3220

Renesas Electronics Europe Limited
Dukes Meadow, Millboard Road, Bourne End, Buckinghamshire, SL8 5FH, U.K
Tel: +44-1628-585-100, Fax: +44-1628-585-900

Renesas Electronics Europe GmbH

Arcadiastrasse 10, 40472 Düsseldorf, Germany Tel: +49-211-65030, Fax: +49-211-6503-1327

Renesas Electronics (China) Co., Ltd.
7th Floor, Quantum Plaza, No.27 ZhiChunLu Haidian District, Beijing 100083, P.R.China
Tei: +86-10-8235-1155, Fax: +86-10-8235-7679

Renesas Electronics (Shanghai) Co., Ltd.
Unit 204, 205, AZIA Center, No. 1233 Lujiazui Ring Rd., Pudong District, Shanghai 200120, China Tel: +86-21-5877-1818, Fax: +86-21-6887-7858 / -7898

Renesas Electronics Hong Kong Limited
Unit 1601-1613, 16/F., Tower 2, Grand Century Place, 193 Prince Edward Road West, Mongkok, Kowloon, Hong Kong
Teit: +852-2886-9318, Fax: +852-2886-9022/9044

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Unit 906, Block B, Menara Amcorp, Amcorp Trade Centre, No. 18, Jln Persiaran Barat, 46050 Petaling Jaya, Selangor Darul Ehsan, Malaysia Tei: +60-3-7955-9390, Fax: +60-3-7955-9510

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